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TLV809

SLVSA03D – JUNE 2010 – REVISED MARCH 2016

## TLV809 3-Pin Supply Voltage Supervisor

Technical

Documents

#### **1** Features

- Precision Supply Voltage Monitor: 2.5 V, 3 V, 3.3 V, 5 V
- Power-On Reset Generator with a Fixed Delay Time of 200 ms
- Supply Current: 9 µA (Typical)
- Temperature Range: -40°C to +85°C
- 3-Pin SOT-23 Package
- Pin-for-Pin Compatible with the MAX809

#### 2 Applications

- DSPs, Microcontrollers, and Microprocessors
- Wireless Communication Systems
- Portable and Battery-Powered Equipment
- Programmable Controls
- Intelligent Instruments
- Industrial Equipment
- Notebook and Desktop Computers
- Automotive Systems

#### 3 Description

Tools &

Software

The TLV809 family of supervisory circuits provides circuit initialization and timing supervision, primarily for digital signal processors (DSPs) and processorbased systems.

Support &

Community

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During power-on, RESET is asserted when the supply voltage ( $V_{DD}$ ) becomes greater than 1.1 V. Thereafter, the supervisory circuit monitors  $V_{DD}$  and keeps RESET active as long as  $V_{DD}$  remains below the threshold voltage,  $V_{IT}$ . An internal timer delays the return of the output to the inactive state (high) to ensure proper system reset. The delay time ( $t_{d(typ)} = 200 \text{ ms}$ ) starts after  $V_{DD}$  rises above the threshold voltage,  $V_{IT}$ . When the supply voltage drops below the  $V_{IT}$  threshold voltage, the output becomes active (low) again. No external components are required. All devices in this family have a fixed sense-threshold voltage ( $V_{IT}$ ) set by an internal voltage divider.

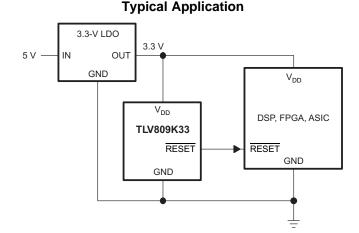
The TLV803 has an active-low, push-pull RESET output. See the TLV803 for an open-drain RESET output and the TLV810 for a push-pull, active-high RESET output.

This product family is designed for supply voltages of 2.5 V, 3 V, 3.3 V, and 5 V. The circuits are available in a 3-pin SOT-23 package. The TLV809 devices are characterized for operation over a temperature range of  $-40^{\circ}$ C to  $+85^{\circ}$ C.

#### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TLV809	SOT-23 (3), DBV	2.90 mm × 1.60 mm
12/009	SOT-23 (3), DBZ	2.92 mm × 1.30 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.



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#### **Revision History**

Ch	anges from Revision C (February 2012) to Revision D Pag
•	Added Device Information table, Pin Configuration and Functions section, ESD Ratings table, Overview section, Feature Description section, Device Functional Modes section, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section.
•	Deleted pinout drawing from page 1
•	Changed Description section: added third paragraph and changed section wording for clarity
•	Changed Voltage Options table: changed title, deleted duplicated data already in POA
•	Deleted soldering temperature parameter from Absolute Maximum Ratings table
•	Changed I <sub>DD</sub> parameter test conditions in <i>Electrical Characteristics</i> table

#### Page

#### Changes from Revision A (July 2010) to Revision B

•	Updated document format to current standards	. 1
•	Added DBZ package to pinout figure	. 1
•	Added DBZ package to Package/Ordering Information table	. 3
•	Added Thermal Information table	. 3
•	Changed Figure 3	. 6

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STRUMENTS

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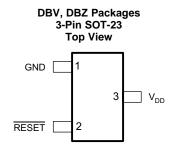
### Page



#### 5 Voltage Options

PRODUCT	THRESHOLD VOLTAGE
TLV809J25	2.25 V
TLV809L30	2.64 V
TLV809K33	2.93 V
TLV809I50	4.55 V

#### 6 Pin Configuration and Functions



#### **Pin Functions**

PIN		I/O	DESCRIPTION		
NO.	NAME	1/0	DESCRIPTION		
1	GND	—	Ground pin. This pin must be connected to ground with a low-impedance connection.		
2	RESET	0	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$		
3 V <sub>DD</sub> I		I	Supply voltage pin. A 0.1- $\mu$ F ceramic capacitor from this pin to ground is recommended to improve stability of the threshold voltage.		

### 7 Specifications

#### 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
V	Supply voltage <sup>(2)</sup>		7	V
V <sub>DD</sub>	All other pins <sup>(2)</sup>	-0.3	7	V
I <sub>OL</sub>	Maximum low output current		5	mA
I <sub>OH</sub>	Maximum high output current		-5	mA
I <sub>IK</sub>	Input clamp current ( $V_I < 0$ or $V_I > V_{DD}$ )		±20	mA
I <sub>OK</sub>	Output clamp current ( $V_O < 0$ or $V_O > V_{DD}$ )		±20	mA
T <sub>A</sub>	Operating free-air temperature	-40	85	°C
T <sub>stg</sub>	Storage temperature	-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to GND. For reliable operation, do not operate the device at 7 V for more than t = 1000h continuously.

STRUMENTS

EXAS

#### 7.2 ESD Ratings

			VALUE	UNIT
V <sub>(ESD)</sub> Elec	Electrostatio discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±2000	
	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±500	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

#### 7.3 Recommended Operating Conditions

at specified temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
$V_{DD}$	Supply voltage	2		6	V
C <sub>IN</sub>	V <sub>DD</sub> bypass capacitor		0.1		μF
T <sub>A</sub>	Operating free-air temperature range	-40		85	°C

#### 7.4 Thermal Information

		TLV	/809	
	THERMAL METRIC <sup>(1)</sup>	DBV (SOT-23)	DBZ (SOT-23)	UNIT
		3 PINS	3 PINS	
$R_{ extsf{ heta}JA}$	Junction-to-ambient thermal resistance	242.1	286.9	°C/W
R <sub>0JC(top)</sub>	Junction-to-case (top) thermal resistance	213.0	105.6	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	123.4	124.4	°C/W
Ψ <sub>JT</sub>	Junction-to-top characterization parameter	45.7	25.8	°C/W
$\Psi_{JB}$	Junction-to-board characterization parameter	130.9	107.9	°C/W
R <sub>0JC(bot)</sub>	Junction-to-case (bottom) thermal resistance		_	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

#### 7.5 Electrical Characteristics

at  $T_A = -40^{\circ}$ C to +85°C (unless otherwise noted); typical values are at  $T_A = 25^{\circ}$ C

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
	High-level output voltage		$V_{DD}$ = 2.5 V to 6 V, $I_{OH}$ = -500 $\mu$ A	V <sub>DD</sub> - 0.2			V
V <sub>OH</sub>			$V_{DD} = 3.3 \text{ V}, \text{ I}_{OH} = -2 \text{ mA}$	$V_{DD} - 0.4$			
			$V_{DD} = 6 V, I_{OH} = -4 mA$	$V_{DD} - 0.4$			
			$V_{DD}$ = 2 V to 6 V, $I_{OH}$ = 500 $\mu$ A			0.2	
V <sub>OL</sub>	Low-level output voltage		$V_{DD} = 3.3 \text{ V}, I_{OH} = 2 \text{ mA}$			0.4	V
			$V_{DD} = 6 \text{ V}, \text{ I}_{OH} = 4 \text{ mA}$			0.4	
	Power-up reset voltage <sup>(1)</sup>		$V_{DD} \ge 1.1 \text{ V}, \text{ I}_{OL} = 50 \mu\text{A}$			0.2	V
	Negative-going input threshold voltage <sup>(2)</sup>	TLV809J25	$T_A = -40^{\circ}C$ to +85°C	2.20	2.25	2.30	V
V		TLV809L30		2.58	2.64	2.70	
V <sub>IT-</sub>		TLV809K33		2.87	2.93	2.99	
		TLV809150		4.45	4.55	4.65	
		TLV809J25			30		
		TLV809L30			35		
V <sub>hys</sub>	Hysteresis	TLV809K33			40		mV
		TLV809150			60		
	Curral currant		V <sub>DD</sub> = 2 V, RESET is unconnected		9	12	۵
I <sub>DD</sub>	Supply current		V <sub>DD</sub> = 6 V, RESET is unconnected		20	25	μA
CI	Input capacitance		$V_{I} = 0 V \text{ to } V_{DD}$		5		pF

(1) The lowest supply voltage at which  $\overline{\text{RESET}}$  becomes active.  $t_{r, VDD} \ge 15 \text{ ms/V}$ .

(2) To ensure best stability of the threshold voltage, place a bypass capacitor (0.1-µF ceramic) near the supply pins.



#### 7.6 Timing Requirements

at T <sub>A</sub> =	= 25°C, $R_L$ = 1 M $\Omega$ , and $C_L$ = 50	) pF				
			MIN	NOM	MAX	UNIT
tw	Pulse duration at V <sub>DD</sub>	$V_{DD} = V_{IT-} + 0.2 \text{ V}, V_{DD} = V_{IT-} - 0.2 \text{ V}$	3			μs

#### 7.7 Switching Characteristics

#### at $T_{\text{A}}$ = 25°C, $R_{\text{L}}$ = 1 MΩ, and $C_{\text{L}}$ = 50 pF

	PARAMETE	R	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t <sub>d</sub>	Delay time		$V_{DD} \ge V_{IT-} + 0.2 \text{ V}$ ; see Figure 1	120	200	280	ms
t <sub>PHL</sub>	Propagation (delay) time, high-to-low-level output	$V_{DD}$ to RESET delay	$V_{IL} = V_{IT-} - 0.2 \text{ V}, V_{IH} = V_{IT-} + 0.2 \text{ V}$		1		μs

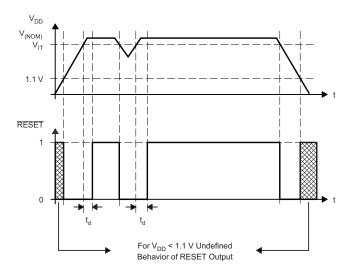
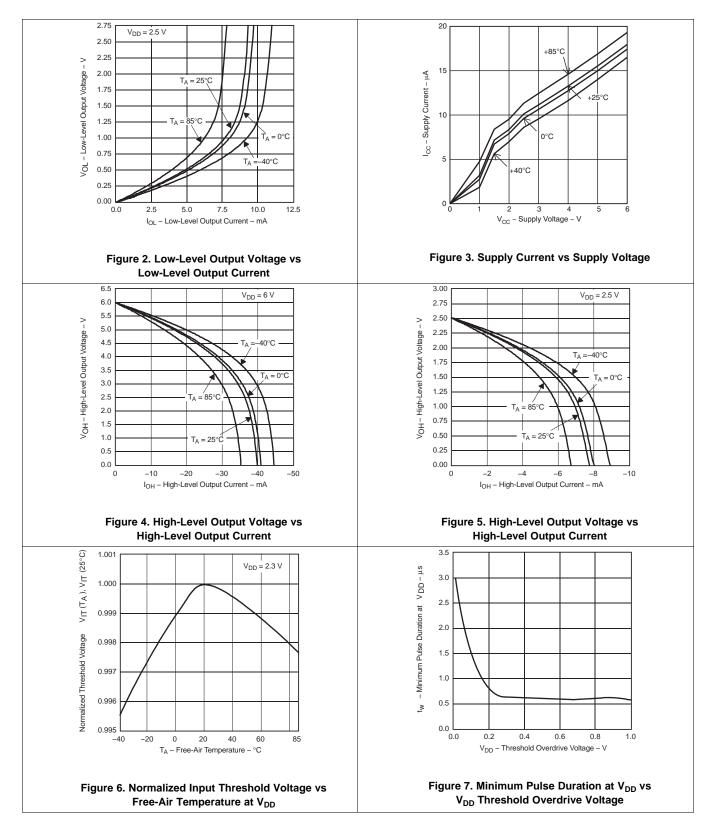


Figure 1. Timing Diagram



#### 7.8 Typical Characteristics



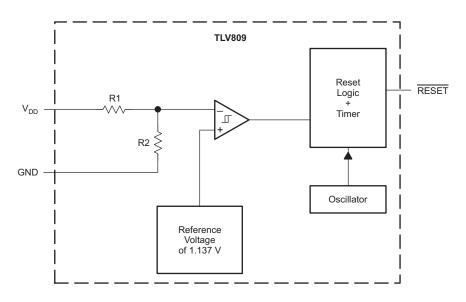


#### 8 Detailed Description

#### 8.1 Overview

The TLV809 is a 3-pin voltage detector with fixed detection thresholds, an active-low push-pull  $\overline{\text{RESET}}$  output, and an internal timer to delay the  $\overline{\text{RESET}}$  signal when  $V_{DD}$  rises above the threshold voltage.

#### 8.2 Functional Block Diagram



#### 8.3 Feature Description

#### 8.3.1 Supply Voltage Monitoring

The device actively monitors its supply voltage to ensure that the power supply is above a certain voltage threshold.

The device offers various fixed threshold options that are approximately 10% below several standard supply voltages (2.5 V, 3.0 V, 3.3 V, 5.0 V).

#### 8.3.2 **RESET** Output

The device has a RESET output to indicate the status of the input power supply.

RESET is an active low signal, asserting when  $V_{DD}$  is below the threshold voltage. When  $V_{DD}$  rises above  $V_{IT}$ , there is a delay time (t<sub>d</sub>) until RESET deasserts.

RESET is a push-pull output stage.

#### 8.4 Device Functional Modes

When the input supply voltage is in its recommended operating range (2 V to 6 V), the device is in a normal operational mode. In normal operational mode the device monitors  $V_{DD}$  for undervoltage detection.

When the input supply is below its recommended operating range, the device is in shutdown mode and therefore tries to assert RESET.

INSTRUMENTS

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#### 9 Application and Implementation

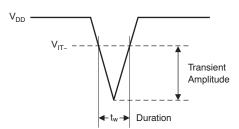
#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

#### 9.1 Application Information

#### 9.1.1 V<sub>DD</sub> Transient Rejection

The device has built-in rejection of fast transients on the  $V_{DD}$  pin. The rejection of transients depends on both the duration and the amplitude of the transient. The amplitude of the transient is measured from the bottom of the transient to the negative threshold voltage of the device, as shown in Figure 8.



#### Figure 8. Voltage Transient Measurement

The device does not respond to transients that are fast duration and low amplitude or long duration and small amplitude. Figure 7 illustrates the relationship between the transient amplitude and duration needed to trigger a reset. Any combination of duration and amplitude above the curve generates a reset signal.

#### 9.1.2 Reset During Power-Up and Power-Down

The device output is valid when  $V_{DD}$  is greater than 1.1 V. When  $V_{DD}$  is less than 1.1 V, the output transistor turns off and becomes high impedance. The voltage on the RESET pin rises to the voltage level connected to the pullup resistor. Figure 9 shows a typical waveform for power-up.

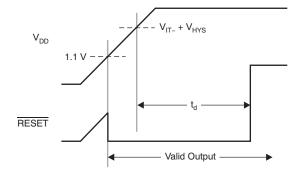


Figure 9. Power-Up Response



#### 9.2 Typical Application

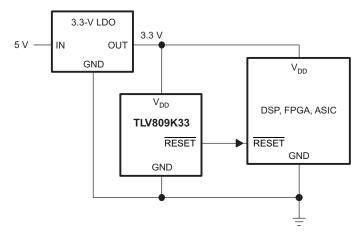


Figure 10. Monitoring a 3.3-V Supply

#### 9.2.1 Design Requirements

The device must ensure that the supply voltage does not drop more than 15% below 3.3 V. If the supply voltage falls below 3.3 V - 15%, then the load must be disabled.

#### 9.2.2 Detailed Design Procedure

The TLV809K33 is selected to ensure that  $V_{DD}$  is greater than 2.87 V when the load is enabled.

#### 9.2.3 Application Curve

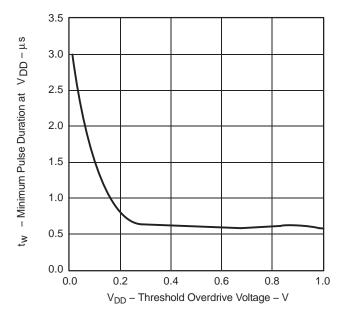


Figure 11. Minimum Pulse Duration at  $V_{DD}$  vs  $V_{DD}$  Threshold Overdrive Voltage



#### 10 Power Supply Recommendations

Power the device with a low-impedance supply. A 0.1- $\mu$ F bypass capacitor from V<sub>DD</sub> to ground is recommended.

#### 11 Layout

#### 11.1 Layout Guidelines

Place the device near the load for the input power supply, with a low-impedance connection to the power supply pins of the load to sense the supply voltage.

#### 11.2 Layout Example

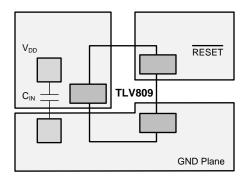


Figure 12. Example Layout



#### **12 Device and Documentation Support**

#### **12.1** Documentation Support

#### 12.1.1 Related Documentation

TLV803 Data Sheet, SBVS157

TLV810 Data Sheet, SBVS158

#### **12.2 Community Resources**

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E<sup>™</sup> Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support TI's Design Support** Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 12.3 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

#### 12.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 12.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

#### 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



22-Dec-2016

## **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	-	Pins	-	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
TLV809I50DBVR	ACTIVE	SOT-23	DBV	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VTBI	Samples
TLV809I50DBVT	ACTIVE	SOT-23	DBV	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VTBI	Samples
TLV809I50DBZR	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	BCMV	Samples
TLV809I50DBZT	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	BCMV	Samples
TLV809J25DBVR	ACTIVE	SOT-23	DBV	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VTCI	Samples
TLV809J25DBVT	ACTIVE	SOT-23	DBV	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VTCI	Samples
TLV809J25DBZR	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	BCMT	Samples
TLV809J25DBZT	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	BCMT	Samples
TLV809K33DBVR	ACTIVE	SOT-23	DBV	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VTRI	Samples
TLV809K33DBVT	ACTIVE	SOT-23	DBV	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VTRI	Samples
TLV809K33DBZR	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	BCMX	Samples
TLV809K33DBZT	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	BCMX	Samples
TLV809L30DBVR	ACTIVE	SOT-23	DBV	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VTXI	Samples
TLV809L30DBVT	ACTIVE	SOT-23	DBV	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VTXI	Samples
TLV809L30DBZR	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	BCMZ	Samples
TLV809L30DBZT	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	BCMZ	Samples

<sup>(1)</sup> The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.





22-Dec-2016

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect. NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design. PREVIEW: Device has been announced but is not in production. Samples may or may not be available. OBSOLETE: TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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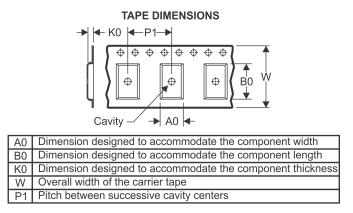
## PACKAGE MATERIALS INFORMATION

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#### TAPE AND REEL INFORMATION





## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV809I50DBVR	SOT-23	DBV	3	3000	180.0	9.0	3.3	3.2	1.47	4.0	8.0	Q3
TLV809I50DBVT	SOT-23	DBV	3	250	180.0	9.0	3.3	3.2	1.47	4.0	8.0	Q3
TLV809I50DBZR	SOT-23	DBZ	3	3000	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
TLV809I50DBZT	SOT-23	DBZ	3	250	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
TLV809J25DBVR	SOT-23	DBV	3	3000	180.0	9.0	3.3	3.2	1.47	4.0	8.0	Q3
TLV809J25DBVT	SOT-23	DBV	3	250	180.0	9.0	3.3	3.2	1.47	4.0	8.0	Q3
TLV809J25DBZR	SOT-23	DBZ	3	3000	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
TLV809J25DBZT	SOT-23	DBZ	3	250	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
TLV809K33DBVR	SOT-23	DBV	3	3000	178.0	9.0	3.3	3.2	1.47	4.0	8.0	Q3
TLV809K33DBVT	SOT-23	DBV	3	250	178.0	8.4	3.3	3.2	1.47	4.0	8.0	Q3
TLV809K33DBZR	SOT-23	DBZ	3	3000	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
TLV809K33DBZT	SOT-23	DBZ	3	250	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
TLV809L30DBVR	SOT-23	DBV	3	3000	180.0	9.0	3.3	3.2	1.47	4.0	8.0	Q3
TLV809L30DBVT	SOT-23	DBV	3	250	180.0	9.0	3.3	3.2	1.47	4.0	8.0	Q3
TLV809L30DBZR	SOT-23	DBZ	3	3000	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
TLV809L30DBZT	SOT-23	DBZ	3	250	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3

TEXAS INSTRUMENTS

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## PACKAGE MATERIALS INFORMATION

22-Dec-2016



*All dimensions are nominal	T				1	[	1
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV809I50DBVR	SOT-23	DBV	3	3000	182.0	182.0	20.0
TLV809I50DBVT	SOT-23	DBV	3	250	182.0	182.0	20.0
TLV809I50DBZR	SOT-23	DBZ	3	3000	203.0	203.0	35.0
TLV809I50DBZT	SOT-23	DBZ	3	250	203.0	203.0	35.0
TLV809J25DBVR	SOT-23	DBV	3	3000	182.0	182.0	20.0
TLV809J25DBVT	SOT-23	DBV	3	250	182.0	182.0	20.0
TLV809J25DBZR	SOT-23	DBZ	3	3000	203.0	203.0	35.0
TLV809J25DBZT	SOT-23	DBZ	3	250	203.0	203.0	35.0
TLV809K33DBVR	SOT-23	DBV	3	3000	180.0	180.0	18.0
TLV809K33DBVT	SOT-23	DBV	3	250	180.0	180.0	18.0
TLV809K33DBZR	SOT-23	DBZ	3	3000	203.0	203.0	35.0
TLV809K33DBZT	SOT-23	DBZ	3	250	203.0	203.0	35.0
TLV809L30DBVR	SOT-23	DBV	3	3000	182.0	182.0	20.0
TLV809L30DBVT	SOT-23	DBV	3	250	182.0	182.0	20.0
TLV809L30DBZR	SOT-23	DBZ	3	3000	203.0	203.0	35.0
TLV809L30DBZT	SOT-23	DBZ	3	250	203.0	203.0	35.0

## DBZ 3

## **GENERIC PACKAGE VIEW**

# SOT-23 - 1.12 mm max height SMALL OUTLINE TRANSISTOR



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



4203227/C

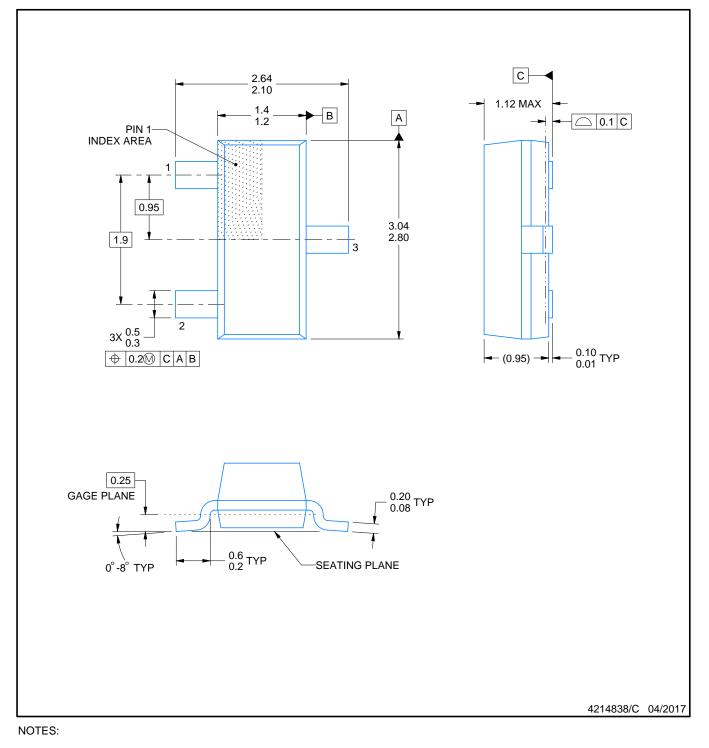
## **DBZ0003A**



## **PACKAGE OUTLINE**

## SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
This drawing is subject to change without notice.
Reference JEDEC registration TO-236, except minimum foot length.



## **DBZ0003A**

## **EXAMPLE BOARD LAYOUT**

## SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

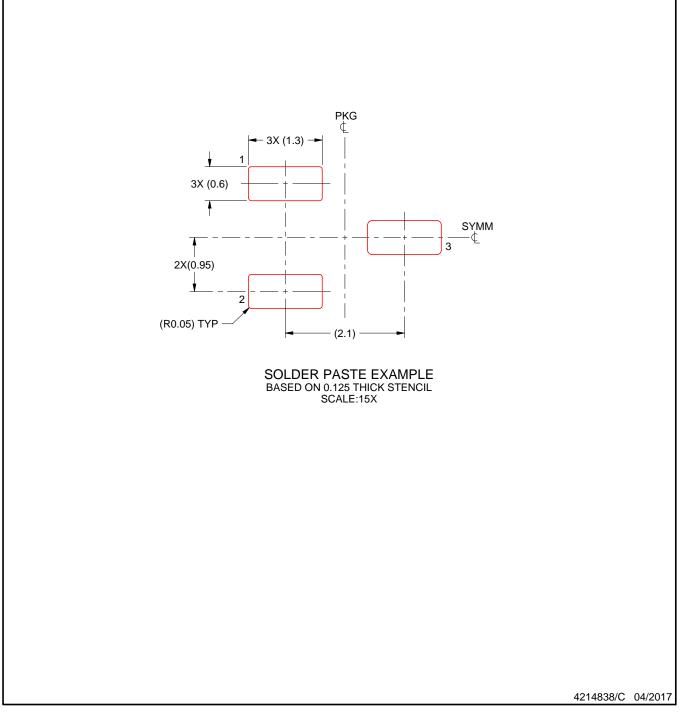


## DBZ0003A

## **EXAMPLE STENCIL DESIGN**

## SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

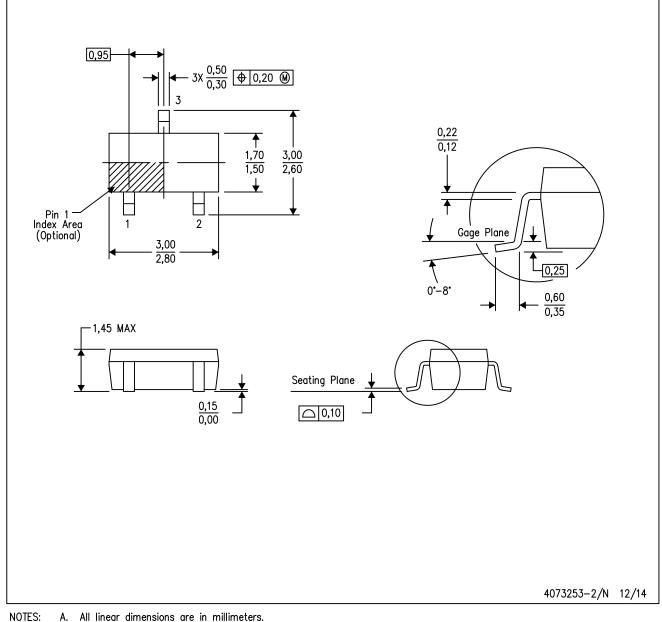
6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

7. Board assembly site may have different recommendations for stencil design.



DBV (R-PDSO-G3)

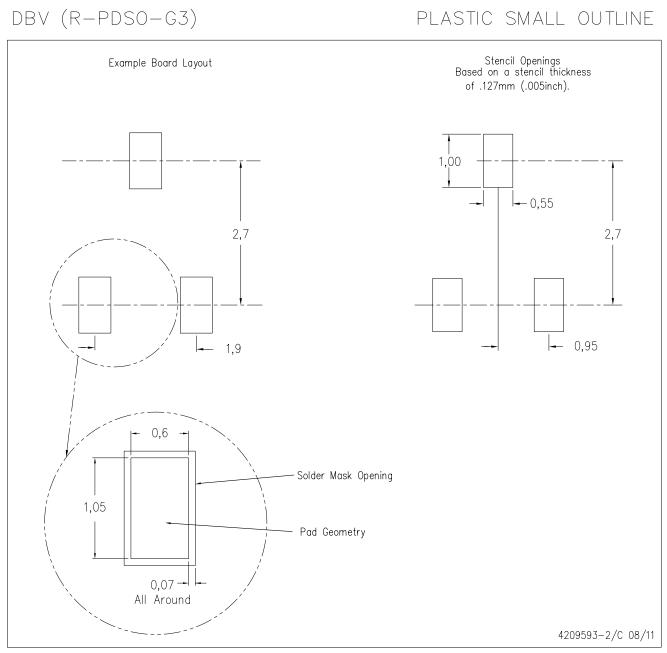
PLASTIC SMALL-OUTLINE PACKAGE



- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.



## LAND PATTERN DATA



NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



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